

SANYO Semiconductors DATA SHEET

FW216 — General-Purpose Switching Device Applications

Features

- · Motor drive applications.
- 4.5V drive.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		35	٧
Gate-to-Source Voltage	VGSS		±20	V
Drain Current (DC)	ID		3.5	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	14	Α
Allowable Power Dissipation	PD	Mounted on a ceramic board (2000mm²X0.8mm) 1unit, PW≤10s	1.6	W
Allowable Power Dissipation	PT	Mounted on a ceramic board (2000mm²X0.8mm), PW≤10s	2.2	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Linit
			min	typ	max	Unit
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	35			V
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =35V, V _{GS} =0V			1	μΑ
Gate-to-Source Leakage Current	IGSS	V _{GS} =±16V, V _{DS} =0V			±10	μΑ
Cutoff Voltage	VGS(off)	VDS=10V, ID=1mA	1.5		2.5	V
Forward Transfer Admittance	yfs	V _{DS} =10V, I _D =3.5A	2.4	4		S
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =3.5A, V _G S=10V		70	90	mΩ
	RDS(on)2	ID=2A, VGS=4.5V		140	196	mΩ
Input Capacitance	Ciss	V _{DS} =10V, f=1MHz		260		pF
Output Capacitance	Coss	V _{DS} =10V, f=1MHz		65		pF
Reverse Transfer Capacitance	Crss	VDS=10V, f=1MHz		40		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit.		9		ns
Rise Time	tr	See specified Test Circuit.		8		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit.		19		ns
Fall Time	tf	See specified Test Circuit.		8		ns

Marking: W216 Continued on next page.

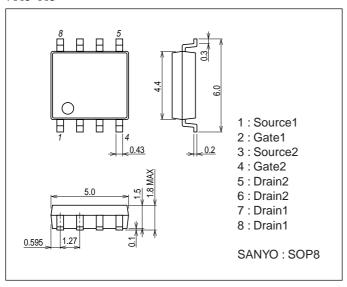
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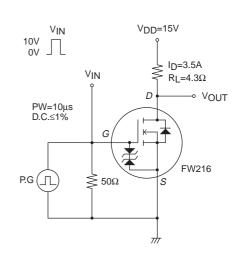
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Onit
Total Gate Charge	Qg	V _{DS} =10V, V _{GS} =10V, I _D =3.5A		6		nC
Gate-to-Source Charge	Qgs	V _{DS} =10V, V _{GS} =10V, I _D =3.5A		1.2		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =10V, V _{GS} =10V, I _D =3.5A		1.0		nC
Diode Forward Voltage	VSD	IS=3.5A, VGS=0V		0.88	1.2	V

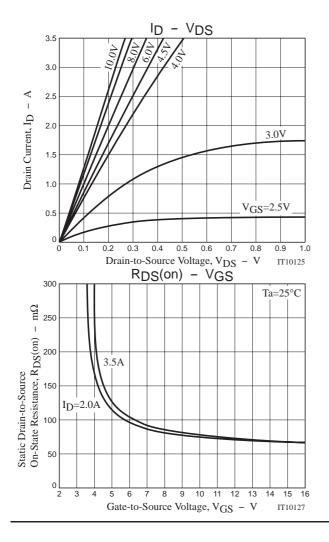
Package Dimensions

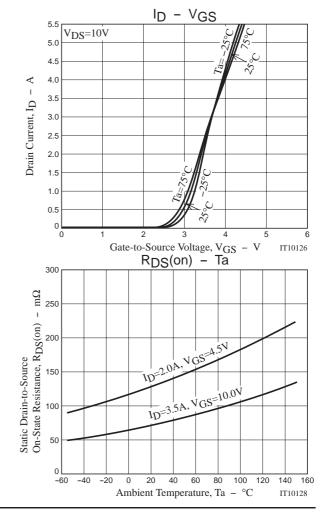
unit : mm 7005-003

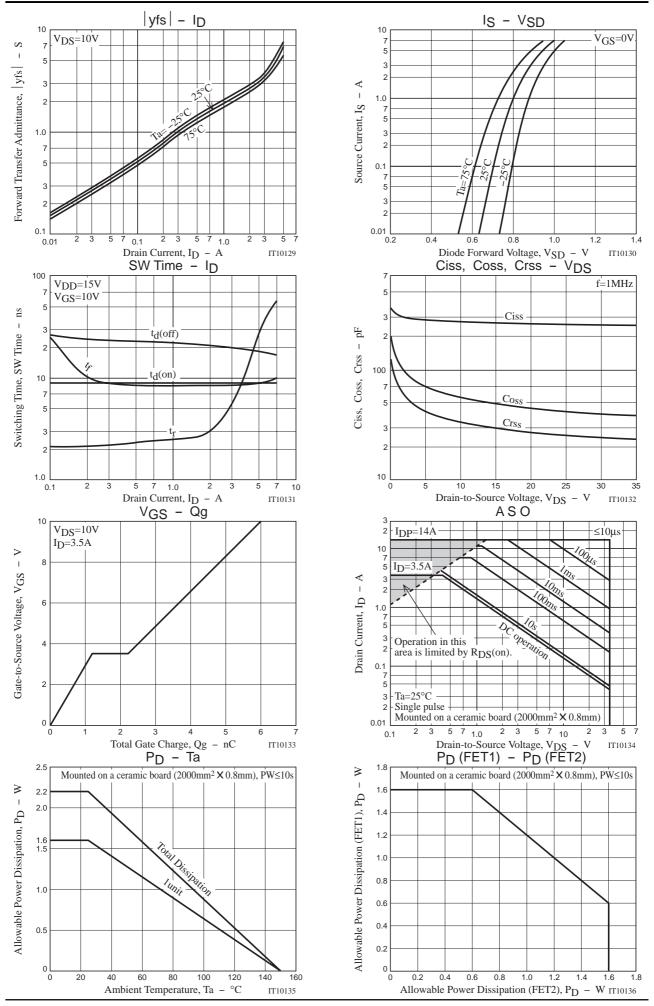


Switching Time Test Circuit









Note on usage : Since the FW216 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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